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With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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# C106 Series

## Sensitive Gate Silicon Controlled Rectifiers Reverse Blocking Thyristors

Glassivated PNP devices designed for high volume consumer applications such as temperature, light, and speed control; process and remote control, and warning systems where reliability of operation is important.

### Features

- Glassivated Surface for Reliability and Uniformity
- Power Rated at Economical Prices
- Practical Level Triggering and Holding Characteristics
- Flat, Rugged, Thermopad Construction for Low Thermal Resistance, High Heat Dissipation and Durability
- Sensitive Gate Triggering
- These are Pb-Free Devices

### MAXIMUM RATINGS ( $T_J = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Max	Unit
Peak Repetitive Off-State Voltage (Note 1) (Sine Wave, 50–60 Hz, $R_{GK} = 1\text{ k}\Omega$ , $T_C = -40^\circ$ to $110^\circ\text{C}$ )	$V_{DRM}$ , $V_{RRM}$		V
	C106B	200	
	C106D, C106D1*	400	
	C106M, C106M1*	600	
On-State RMS Current ( $180^\circ$ Conduction Angles, $T_C = 80^\circ\text{C}$ )	$I_{T(RMS)}$	4.0	A
Average On-State Current ( $180^\circ$ Conduction Angles, $T_C = 80^\circ\text{C}$ )	$I_{T(AV)}$	2.55	A
Peak Non-Repetitive Surge Current (1/2 Cycle, Sine Wave, 60 Hz, $T_J = +25^\circ\text{C}$ )	$I_{TSM}$	20	A
Circuit Fusing Considerations ( $t = 8.3\text{ ms}$ )	$I^2t$	1.65	$\text{A}^2\text{s}$
Forward Peak Gate Power (Pulse Width $\leq 1.0\ \mu\text{sec}$ , $T_C = 80^\circ\text{C}$ )	$P_{GM}$	0.5	W
Forward Average Gate Power (Pulse Width $\leq 1.0\ \mu\text{sec}$ , $T_C = 80^\circ\text{C}$ )	$P_{G(AV)}$	0.1	W
Forward Peak Gate Current (Pulse Width $\leq 1.0\ \mu\text{sec}$ , $T_C = 80^\circ\text{C}$ )	$I_{GM}$	0.2	A
Operating Junction Temperature Range	$T_J$	-40 to +110	$^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	-40 to +150	$^\circ\text{C}$
Mounting Torque (Note 2)	-	6.0	in. lb.

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

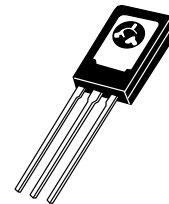
1.  $V_{DRM}$  and  $V_{RRM}$  for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.
2. Torque rating applies with use of compression washer (B52200F006). Mounting torque in excess of 6 in. lb. does not appreciably lower case-to-sink thermal resistance. Anode lead and heatsink contact pad are common.



Expertise Applied | Answers Delivered

Littelfuse.com

**SCRs**  
**4 A RMS, 200 – 600 Volts**



TO-225AA  
CASE 077  
STYLE 2

### MARKING DIAGRAM & PIN ASSIGNMENT



- Y = Year
- WW = Work Week
- C106xx = Device Code
- xx = B, D, D1, M, M1
- G = Pb-Free Package

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

# C106 Series

## THERMAL CHARACTERISTICS (T<sub>C</sub> = 25°C unless otherwise noted.)

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	R <sub>θJC</sub>	3.0	°C/W
Thermal Resistance, Junction-to-Ambient	R <sub>θJA</sub>	75	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8 in. from Case for 10 Seconds	T <sub>L</sub>	260	°C

## ELECTRICAL CHARACTERISTICS (T<sub>C</sub> = 25°C unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
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### OFF CHARACTERISTICS

Peak Repetitive Forward or Reverse Blocking Current (V <sub>AK</sub> = Rated V <sub>DRM</sub> or V <sub>R<sub>RRM</sub></sub> , R <sub>GK</sub> = 1 kΩ)	T <sub>J</sub> = 25°C T <sub>J</sub> = 110°C	I <sub>DRM</sub> , I <sub>R<sub>RRM</sub></sub>	-	-	10	μA
			-	-	100	μA

### ON CHARACTERISTICS

Peak Forward On-State Voltage (Note 3) (I <sub>TM</sub> = 4 A)		V <sub>TM</sub>	-	-	2.2	V
Gate Trigger Current (Continuous dc) (Note 4) (V <sub>AK</sub> = 6 Vdc, R <sub>L</sub> = 100 Ω)	T <sub>J</sub> = 25°C T <sub>J</sub> = -40°C	I <sub>GT</sub>	-	15	200	μA
			-	35	500	
Peak Reverse Gate Voltage (I <sub>GR</sub> = 10 μA)		V <sub>G<sub>RM</sub></sub>	-	-	6.0	V
Gate Trigger Voltage (Continuous dc) (Note 4) (V <sub>AK</sub> = 6 Vdc, R <sub>L</sub> = 100 Ω)	T <sub>J</sub> = 25°C T <sub>J</sub> = -40°C	V <sub>GT</sub>	0.4	0.60	0.8	V
			0.5	0.75	1.0	
Gate Non-Trigger Voltage (Continuous dc) (Note 4) (V <sub>AK</sub> = 12 V, R <sub>L</sub> = 100 Ω, T <sub>J</sub> = 110°C)		V <sub>GD</sub>	0.2	-	-	V
Latching Current (V <sub>AK</sub> = 12 V, I <sub>G</sub> = 20 mA, R <sub>GK</sub> = 1 kΩ)	T <sub>J</sub> = 25°C T <sub>J</sub> = -40°C	I <sub>L</sub>	-	0.20	5.0	mA
			-	0.35	7.0	
Holding Current (V <sub>D</sub> = 12 Vdc) (Initiating Current = 20 mA, R <sub>GK</sub> = 1 kΩ)	T <sub>J</sub> = 25°C T <sub>J</sub> = -40°C T <sub>J</sub> = +110°C	I <sub>H</sub>	-	0.19	3.0	mA
			-	0.33	6.0	
			-	0.07	2.0	

### DYNAMIC CHARACTERISTICS

Critical Rate-of-Rise of Off-State Voltage (V <sub>AK</sub> = Rated V <sub>DRM</sub> , Exponential Waveform, R <sub>GK</sub> = 1 kΩ, T <sub>J</sub> = 110°C)		dv/dt	-	8.0	-	V/μs
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3. Pulse Test: Pulse Width ≤ 2.0 ms, Duty Cycle ≤ 2%.
4. R<sub>GK</sub> is not included in measurement.

# C106 Series

## Voltage Current Characteristic of SCR

Symbol	Parameter
$V_{DRM}$	Peak Repetitive Off State Forward Voltage
$I_{DRM}$	Peak Forward Blocking Current
$V_{RRM}$	Peak Repetitive Off State Reverse Voltage
$I_{RRM}$	Peak Reverse Blocking Current
$V_{TM}$	Peak On State Voltage
$I_H$	Holding Current

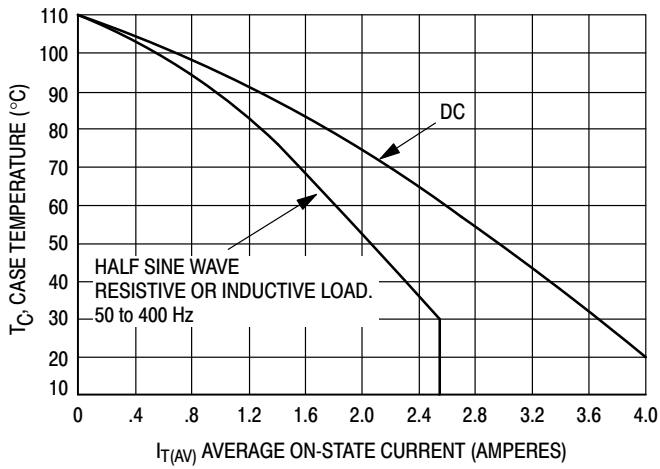
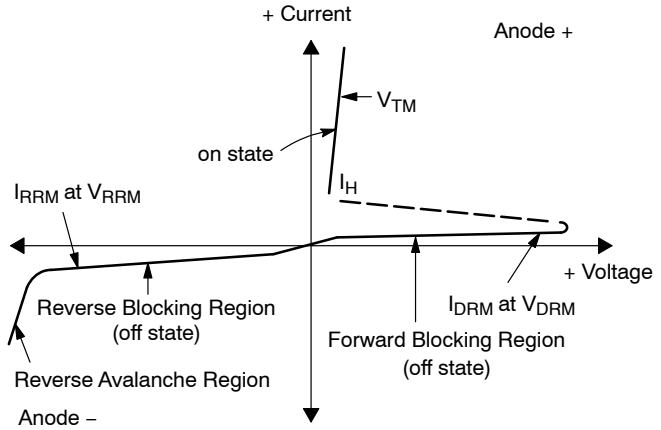


Figure 1. Average Current Derating

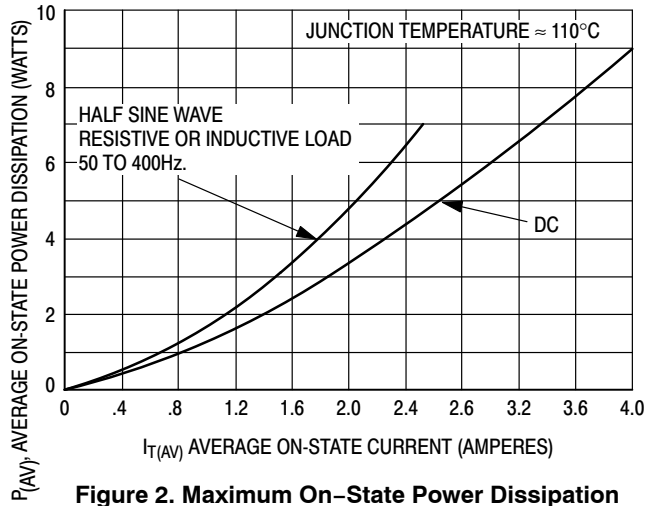
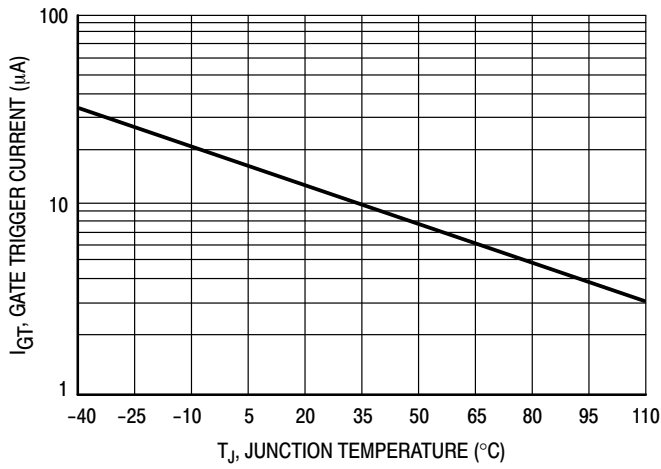
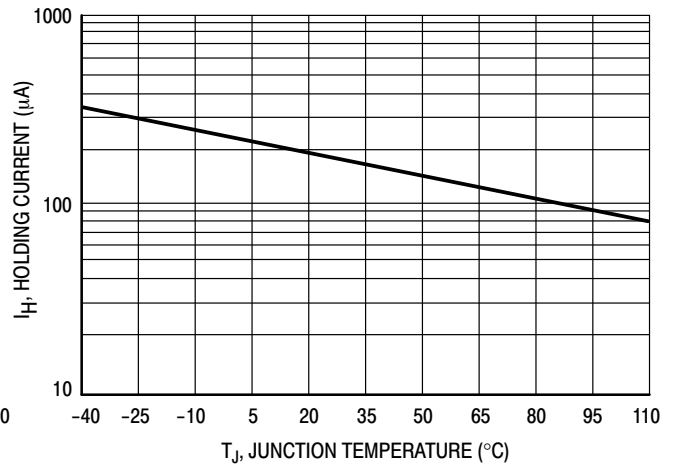


Figure 2. Maximum On-State Power Dissipation

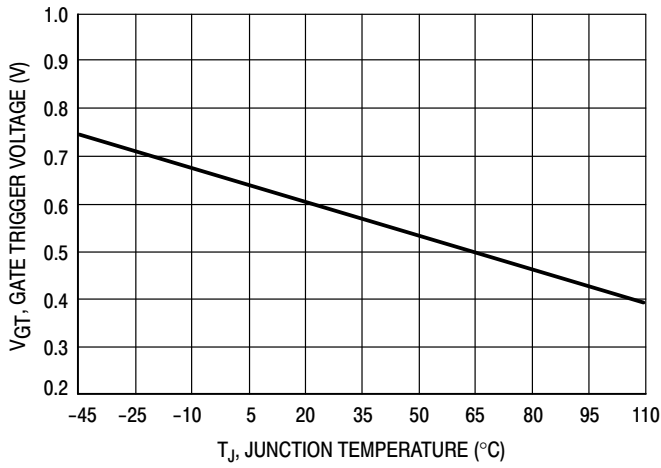
# C106 Series



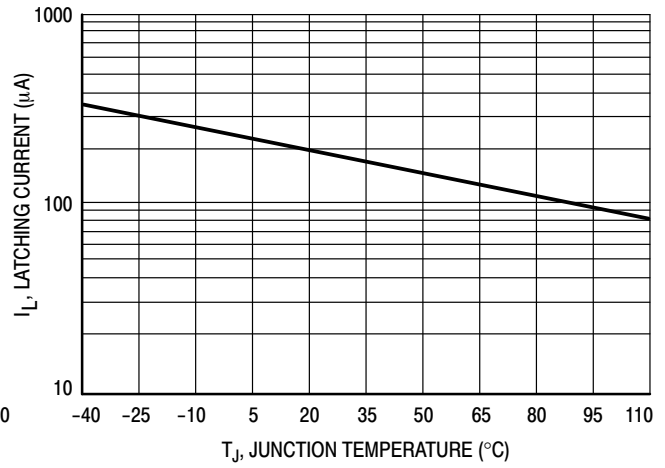
**Figure 3. Typical Gate Trigger Current versus Junction Temperature**



**Figure 4. Typical Holding Current versus Junction Temperature**



**Figure 5. Typical Gate Trigger Voltage versus Junction Temperature**

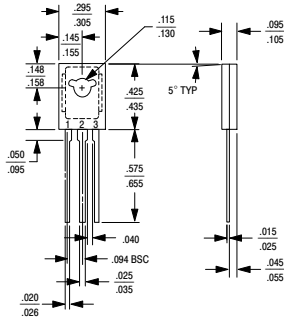


**Figure 6. Typical Latching Current versus Junction Temperature**

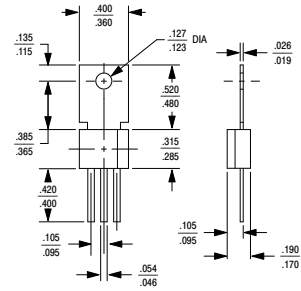
# C106 Series

## PACKAGE INTERCHANGEABILITY

The dimensional diagrams below compare the critical dimensions of the Littelfuse C-106 package with competitive devices. It has been demonstrated that the smaller dimensions of the Littelfuse package make it compatible in most lead-mount and chassis-mount applications. The user is advised to compare all critical dimensions for mounting compatibility.



Littelfuse C-106 Package



Competitive C-106 Package

### ORDERING INFORMATION

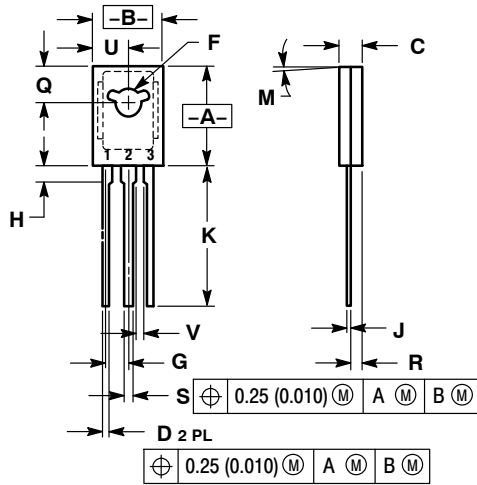
Device	Package	Shipping <sup>†</sup>
C106BG	TO-225AA (Pb-Free)	500 Units / Box
C106DG	TO-225AA (Pb-Free)	500 Units / Box
C106D1G*	TO-225AA (Pb-Free)	500 Units / Box
C106MG	TO-225AA (Pb-Free)	500 Units / Box
C106M1G*	TO-225AA (Pb-Free)	500 Units / Box

\*D1 signifies European equivalent for D suffix and M1 signifies European equivalent for M suffix.

# C106 Series

## PACKAGE DIMENSIONS

TO-225  
CASE 77-09  
ISSUE Z



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. 077-01 THRU -08 OBSOLETE, NEW STANDARD 077-09.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.425	0.435	10.80	11.04
B	0.295	0.305	7.50	7.74
C	0.095	0.105	2.42	2.66
D	0.020	0.026	0.51	0.66
F	0.115	0.130	2.93	3.30
G	0.094 BSC		2.39 BSC	
H	0.050	0.095	1.27	2.41
J	0.015	0.025	0.39	0.63
K	0.575	0.655	14.61	16.63
M	5° TYP		5° TYP	
Q	0.148	0.158	3.76	4.01
R	0.045	0.065	1.15	1.65
S	0.025	0.035	0.64	0.88
U	0.145	0.155	3.69	3.93
V	0.040	---	1.02	---

STYLE 2:

1. CATHODE
2. ANODE
3. GATE

Littelfuse products are not designed for, and shall not be used for, any purpose (including, without limitation, automotive, military, aerospace, medical, life-saving, life-sustaining or nuclear facility applications, devices intended for surgical implant into the body, or any other application in which the failure or lack of desired operation of the product may result in personal injury, death, or property damage) other than those expressly set forth in applicable Littelfuse product documentation. Warranties granted by Littelfuse shall be deemed void for products used for any purpose not expressly set forth in applicable Littelfuse documentation. Littelfuse shall not be liable for any claims or damages arising out of products used in applications not expressly intended by Littelfuse as set forth in applicable Littelfuse documentation. The sale and use of Littelfuse products is subject to Littelfuse Terms and Conditions of Sale, unless otherwise agreed by Littelfuse.

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